PCN Number:	20211123	000.2		PCN I	Date:	December 28, 2021				
Title: Qualifica	ation of a ne	ew BOM f	or select	devices in the SOIC	package					
<b>Customer Conta</b>	ct: <u>PCN M</u>	<u>Nanager</u>	Dept:							
Proposed 1 <sup>st</sup> Sh	ip Date:	June 2	8 2022	Sample		provided at				
Change Type:				ilability:	samp	ole request				
Assembly Sit	e		Design		Waf	er Bum	n Site			
Assembly Pro			Data S	heet			p Material			
Assembly Ma	terials		Part nu	imber change	🗌 Waf	er Bum	p Process			
Mechanical S	•		Test Si	te	Waf	er Fab S	Site			
Packing/Ship	ping/Labelir	ng	Test Pr	ocess			Materials			
					Waf	er Fab I	Process			
			PCN	Details						
Description of C	hange:									
This PCN is to inform of the qualification of a new BOM for the devices in the product affected section as follows:										
V	Vhat			Current		New				
Mount	Compound			4042500		4147	/858			
Mold C	Compound			4205694		4211	.880			
Leadfr	ame Prep		Non	-Roughened		Rough	ened			
Reason for Char	nge:									
Continuity of supp	bly									
Anticipated imp	act on For	m, Fit, F	unction,	Quality or Reliabil	ity (posi	tive /	negative):			
None										
Impact on Envir	onmental	Ratings								
	Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.									
RoHS		RE	АСН	Green Statu	IS	IEC	62474			
🛛 No Change	$\square$	No Char	nge	🛛 No Change	$\geq$	🛛 No Ch	ange			
Changes to proc	luct identi	fication	resulting	from this PCN:						
None										
Product Affected	d:									
MLA00149DR	SN65	5HVD1040	AQDRQ1	SN65HVD1050AQDRC	21 SN65	HVDA10	40AQDRQ1			
MLA00312DR	SN65	5HVD1040	QDRQ1	SN65HVD1050QDRQ	SN65	SN65HVDA1050AQDRQ1				



# Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

#### SOIC/SOP/SSOP Automotive UBOM Enterprise Qualification in TITL Approved 03-Dec-2018

#### Product Attributes

Attributes	Qual Device: LT1014DMDW	Qual Device: <u>SN0302035DWRG4</u>	Qual Device: TPIC6A595DWR
Automotive Grade Level	-	Grade 1	Grade 1
Operating Temp Range	-55 to +125 C	-40 to +125 C	-40 to +125 C
Product Function	Signal Chain	Signal Chain	Power Management
Wafer Fab Supplier	SFAB	DFAB	DFAB
Die Revision	J	C	С
Assembly Site	TAI	TAI	TAI
Package Type	SOIC	SOIC	SOIC
Package Designator	DW	DW	DW
Ball/Lead Count	16	20	24

- QBS: Qual By Similarity
- Qual Device qualified at LEVEL1-260CG: LT1014DMDW and TPIC6A595DWR
- Qual Device qualified at LEVEL3-260CG: SN0302035DWRG4
- Device LT1014DMDW contains multiple dies.

Туре	#	Test Spec	Min Lot Qty	SS/Lot	Test Name / Condition	Duration	Qual Device: <u>LT1014DMDW</u>	Qual Device: <u>SN0302035DWRG4</u>	Qual Device: TPIC6A595DWR
		Test Grou	ıp A – Accel	erated En	vironment Stress Tests				
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Automotive Preconditioning	Level 1-260C	No Fails	-	No Fails
PC	A1	JEDEC J-STD-020 JESD22-A113	3	77	Automotive Preconditioning	Level 3-260C	-	No Fails	-
AC	A3	JEDEC JESD22-A102	3	77	Autoclave 121C	96 Hours	2/154/0	3/231/0	3/231/0
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -55/125C	1000 Cycles	2/153/0 (1)	-	-
TC	A4	JEDEC JESD22-A104 and Appendix 3	3	77	Temperature Cycle, -55/150C	1000 Cycles	-	3/228/0 (2)	3/231/0
TC- BP	A4	MIL-STD883 Method 2011	1	30	Post TC Bond Pull	Wires	2/60/0	3/90/0	3/90/0
PTC	A5	JEDEC JESD22-A105	1	45	Power Temperature Cycle	1000 Cycles	N/A	N/A	N/A
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 150C	1000 Hours	2/90/0	-	-
HTSL	A6	JEDEC JESD22-A103	1	45	High Temp Storage Bake 175C	500 Hours	-	3/135/0	3/135/0
		Test Grou	ıp B – Acce	lerated Lif	fetime Simulation Tests				
EDR	B3	AEC Q100-005	3	77	NVM Endurance, Data Retention, and Operational Life	-	N/A	N/A	N/A
		Test Gr	oup C - Pao	kage Ass	embly Integrity Tests				
WBS	C1	AEC Q100-001	1	30	Wire Bond Shear (Cpk>1.67)	Wires	2/60/0	3/90/0	3/90/0
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull (Cpk>1.67)	Wires	2/60/0	3/90/0	3/90/0
SD	C3	JEDEC JESD22-B102	1	15	Solderability	>95% Lead Coverage	2/30/0	3/45/0	3/45/0
PD	C4	JEDEC JESD22-B100 and B108	3	10	Physical Dimensions (Cpk>1.67)	-	2/20/0	3/30/0	3/30/0
LI	C6	JEDEC JESD22-B105	1	50	Lead Integrity	-	-	-	-

	Ī	Test (	Group D – Die	e Fa	bric	ation Reliability Tests				
F	м	D1	JESD61		-	Electromigration		Completed Per Process	Completed Per Process	Completed Per Process
	_1VI		JESDOT	-	-	Liectionigration	-	Technology Requirements	Technology Requirements	Technology Requirements
TD	DDB	D2	JESD35			Time Dependant Dielectric		Completed Per Process	Completed Per Process	Completed Per Process
		02	JE3D35	-	-	Breakdown	-	Technology Requirements	Technology Requirements	Technology Requirements
н	ICI	D3	JESD60 &			Hot Injection Carrier		Completed Per Process	Completed Per Process	Completed Per Process
		03	28	-	-	Hot injection Carrier	-	Technology Requirements	Technology Requirements	Technology Requirements
NI	BTI	D4	_			Negative Bias Temperature		Completed Per Process	Completed Per Process	Completed Per Process
		04	-	-	-	Instability	-	Technology Requirements	Technology Requirements	Technology Requirements
	SM	D5				Stress Migration		Completed Per Process	Completed Per Process	Completed Per Process
3	IVI	DS	-	-	- Stress Migration		-	Technology Requirements	Technology Requirements	Technology Requirements

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Ambient Operating Temperature by Automotive Grade Level: Grade 0 (or E):  $-40^{\circ}$ C to  $+150^{\circ}$ C Grade 1 (or Q):  $-40^{\circ}$ C to  $+125^{\circ}$ C Grade 2 (or T):  $-40^{\circ}$ C to  $+105^{\circ}$ C Grade 3 (or I):  $-40^{\circ}$ C to  $+85^{\circ}$ C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold: HTOL, ED Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room: AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

Note (1): 1 unit was missing/lost before test. Note (2): 3 units were missing/lost before test.

TI Qualification ID: 20180507-125733



TI Information Selective Disclosure

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# Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

### Enterprise Qualification (Automotive) - SOIC Gen 2 Hyde D with Consolidated Leadframe Approved 13-Sep-2021

#### Product Attributes

Attributes	Qual Device: <u>CD4093BQM96Q1</u>	Qual Device: K3HVD1781QDRQ1	Qual Device: <u>SE555DR</u>	Qual Device: <u>SN103592DR</u>	Qual Device: <u>SN74HC S08QDRQ1</u>	Qual Device: TCAN1043GDRQ1	Qual Device: TCAN1044VDRQ1	Qual Device: TLC5916QDRQ1	Qual Device: TMS3705DDRQ1	
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1	Grade 3	
Operating Temp Range	-40 to +125 C	-40 to +125 C	-55 to +125 C	-40 to +125 C -40 to +125 C		-55 to +125 C	-40 to +125 C	-40 to +125 C	-40 to +85 C	
Product Function	Signal Chain	Signal Chain	Signal Chain	Power Management	Signal Chain	Signal Chain	Signal Chain	Power Management	Logic	
Wafer Fab Supplier	SH-BIP-1	DP1DM5	SH-BIP-1	SH-BIP-1	RFAB	MH8	RFAB	MH8	DL-LIN	
Die Revision	-	-	В	С	B0	С	PG2.0	-	С	
Assembly Site	FMX	MLA	TAI	TAI	MLA	FMX	MLA	FMX	TAI	
Package Type	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	SOIC	
Package Designator	D	D	D	D	D	D	D	D	D	
Ball/Lead Count	14	8	8	8	14	14	8	16	16	

- QBS: Qual By Similarity

- Qual Devices CD4093BQM96Q1, K3HVD1781QDRQ1, SE555DR, SN103592DR, SN74HCS08QDRQ1, TCAN1043GDRQ1, TCAN1044VDRQ1\_TLC5916QDRQ1 are qualified at LEVEL1-260CG - Qual Device TMS3705DDRQ1 is qualified at LEVEL3-260CG

Qualification Results
Data Displayed as: Number of lots / Total sample size / Total failed

	Typ e	#	Test Spec	Mi L Ot Qt Y	SS/L ot	Test Name / Condition	Durati on	Qual Device: <u>CD4093BQ</u> <u>M96Q1</u>	Qual Device: <u>K3HVD1781Q</u> <u>DRQ1</u>	Qual Device: <u>SE555DR</u>	Qual Device: <u>SN103592</u> <u>DR</u>	Qual Device: <u>SN74HC S08Q</u> DRQ1	Qual Device: <u>TCAN1043G</u> <u>DRQ1</u>	Qual Device: <u>TCAN1044V</u> <u>DRQ1</u>	Qual Device: <u>TLC5916Q</u> <u>DRQ1</u>	Qual Device: <u>TMS3705D</u> <u>DRQ1</u>
Te	est Gr	oup /		lerate	d Envir	onment Stres	s Tests									
	AC	A 3	JEDE C JESD 22- A102	3	77	Autoclave 121C	96 Hours	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
	тс	A 4	JEDE C JESD 22- A104 and Appen dix 3	3	77	Temperatu re Cycle, - 65/150C	500 Cycle s	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
	PT C	A 5	JEDE C JESD 22- A105	1	45	Power Temperatu re Cycle	1000 Cycle s	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
Ť	est Gr	oup	B – Acce	lerate	ed Lifeti	me Simulation	n Tests									
	ED R	B 3	AEC Q100- 005	3	77	NVM Endurance , Data Retention, and Operationa I Life	-	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
	Test (	Grou		ckage	Assem	bly Integrity	Tests									
	WB S	C 1	AEC Q100- 001	1	30	Wire Bond Shear (Cpk>1.67)	-	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0
	WB P	C 2	MIL- STD8 83 Metho	1	30	Wire Bond Pull (Cpk>1.67)	-	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0	3/90/0

	Typ e	#	Test Spec	Mi L Ot Qt Y	SS/L ot	Test Name / Condition	Durati on	Qual Device: <u>CD4093BQ</u> <u>M96Q1</u>	Qual Device: <u>K3HVD1781Q</u> <u>DRQ1</u>	Qual Device: <u>SE555DR</u>	Qual Device: <u>SN103592</u> <u>DR</u>	Qual Device: <u>SN74HC S08Q</u> <u>DRQ1</u>	Qual Device: <u>TCAN1043G</u> <u>DRQ1</u>	Qual Device: <u>TCAN1044V</u> <u>DRQ1</u>	Qual Device: <u>TLC5916Q</u> <u>DRQ1</u>	Qual Device: <u>TMS3705D</u> <u>DRQ1</u>
Π			d 2011													
	SD	C 3	JEDE C JESD 22- B102	1	15	Surface Mount Solderabilit y >95% Lead Coverage	PB- Free Solder	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0	3/45/0
	PD	C 4	JEDE C JESD 22- B100 and B108	3	10	Physical Dimension s (Cpk>1.67)	-	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0	3/30/0
	SB S	C 5	AEC Q100- 010	3	50	Solder Ball Shear (Cpk>1.67)	Solder Balls	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A	N/A
	U	C 6	JEDE C JESD 22- B105	1	50	Lead Fatigue	Leads	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0	3/66/0
	U	C 6	JEDE C JESD 22- B105	1	50	Lead Pull	Leads	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0	3/72/0
	Test	Gro	up D – Di	e Fab	ricatio	n Reliability To	ests									
	EM	D 1	JESD 61	-	-	Electromigr ation	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
	TD DB	D 2	JESD 35	-	-	Time Dependant Dielectric Breakdown	-	Completed Per Process Technology	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy	Complete d Per Process Technolo gy	Completed Per Process Technology Requirement s	Completed Per Process Technology	Completed Per Process Technology	Complete d Per Process Technolog y	Completed Per Process Technolog y

Typ e	#	Test Spec	Mi L Ot Y	SS/L ot	Test Name / Condition	Durati on	Qual Device: <u>CD4093BQ</u> <u>M96Q1</u>	Qual Device: <u>K3HVD1781Q</u> <u>DRQ1</u>	Qual Device: <u>SE555DR</u>	Qual Device: <u>SN103592</u> <u>DR</u>	Qual Device: <u>SN74HC S08Q</u> DRQ1	Qual Device: <u>TCAN1043G</u> <u>DRQ1</u>	Qual Device: <u>TCAN1044V</u> <u>DRQ1</u>	Qual Device: <u>TLC5916Q</u> <u>DRQ1</u>	Qual Device: <u>TMS3705D</u> <u>DRQ1</u>
							Requireme nts		Requirem ents	Requirem ents		Requireme nts	Requireme nts	Requirem ents	Requirem ents
HCI	D 3	JESD 60 & 28	-	-	Hot Injection Carrier	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
NB TI	D 4	-	-	-	Negative Bias Temperatu re Instability	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents
SM	D 5	-	-	-	Stress Migration	-	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requiremen ts	Complete d Per Process Technolo gy Requirem ents	Complete d Per Process Technolo gy Requirem ents	Completed Per Process Technology Requirement s	Completed Per Process Technology Requireme nts	Completed Per Process Technology Requireme nts	Complete d Per Process Technolog y Requirem ents	Completed Per Process Technolog y Requirem ents

#### A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

 $\begin{array}{l} \mbox{Ambient Operating Temperature by Automotive Grade Level:} \\ \mbox{Grade 0 (or E): -40^{\circ}C to +150^{\circ}C} \\ \mbox{Grade 1 (or Q): -40^{\circ}C to +125^{\circ}C} \\ \mbox{Grade 2 (or T): -40^{\circ}C to +105^{\circ}C} \\ \mbox{Grade 3 (or 1): -40^{\circ}C to +85^{\circ}C} \end{array}$ 

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold: HTOL. ED

Room/Hot: THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room: AC/uHAST

Green/Pb-free Status: Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20201023-136790

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